11/03/2013 www.crouzet.com



Bare board version NB20 Part number 88970013



- For easy and discreet integration into your applications
- For mass-production applications
- Memory: 120 lines in LADDER language and up to 350 "typical" blocks in FBD language
- Compact dimensions
- Range of controllers for use with application specific functions

| | um | |
|--|----|--|
| | | |
| | | |

| Туре | Input | Output | Supply |
|----------------------|------------|----------|--------------|
| 88970013 NB20 | 12 digital | 8 relays | 100 →240 VAC |

Specifications

| Certifications | CE, UL, CSA, GL |
|---|---|
| Conformity to standards (with the low voltage directive | IEC/EN 61131-2 (Open equipment) |
| and EMC directive) | IEC/EN 61131-2 (Open equipment) IEC/EN 61131-2 (Zone B) IEC/EN 61000-6-2, IEC/EN 61000-6-3 (*) IEC/EN 61000-6-4 (*) Except configuration (88 970 1.1 or 88 970 1.2) + (88 970 250 or 88 970 270) + 88 970 241 class A (class B in a metal enclosure) |
| Earthing | Not included |
| Protection rating | In accordance with IEC/EN 60529 : |
| Trocolor rating | IP40 on front panel IP20 on terminal block |
| Overvoltage category | 3 in accordance with IEC/EN 60664-1 |
| Pollution | Degree : 2 in accordance with IEC/EN 61131-2 |
| Max operating Altitude | Operation : 2000 m Transport : 3048 m |
| Mechanical resistance | Immunity to vibrations IEC/EN 60068-2-6, test Fc Immunity to shock IEC/EN 60068-2-27, test Ea |
| Resistance to electrostatic discharge | Immunity to ESD IEC/EN 61000-4-2, level 3 |
| Resistance to HF interference | Immunity to radiated electrostatic fields IEC/EN 61000-4-3 Immunity to fast transients (burst immunity) IEC/EN 61000-4-4, level 3 Immunity to shock waves IEC/EN 61000-4-5 Radio frequency in common mode IEC/EN 61000-4-6, level 3 Voltage dips and breaks (AC) IEC/EN 61000-4-11 Immunity to damped oscillatory waves IEC/EN 61000-4-12 |
| Conducted and radiated emissions | Class B (*) in accordance with EN 55022, EN 55011 (CISPR22, CISPR11) group 1 (*) Except configuration (88 970 1.1 or 88 970 1.2) + (88 970 250 or 88 970 270) + 88 970 241 class A (class B in a metal enclosure) |
| Operating temperature | -20 →+70 °C except CB and XB versions in VDC : -30 →+70 °C in accordance with IEC/EN 60068-2-1 and IEC/EN 60068-2-2 |
| Storage temperature | -40 →+70 °C in accordance with IEC/EN 60068-2-1 and IEC/EN 60068-2-2 |
| Relative humidity | 95 % max. (no condensation or dripping water) in accordance with IEC/EN 60068-2-30 |
| Mounting | On symmetrical DIN rail, 35 x 7.5 mm and 35 x 15 mm, or on panel (2 x Ø 4 mm) |
| Screw terminals connection capacity | Flexible wire with ferrule = |
| | 1 conductor : 0.25 to 2.5 mm ² (AWG 24AWG 14) |
| | 2 conductors 0.25 to 0.75 mm ² (AWG 24AWG 18) Semi-rigid wire = |
| | 1 conductor : 0.2 to 2.5 mm ² (AWG 25AWG 14) Rigid wire = |
| | 1 conductor : 0.2 to 2.5 mm ² (AWG 25AWG 14) |
| | 2 conductors 0.2 to 1.5 mm ² (AWG 25AWG 16) |
| | Tightening torque = |
| | 0.5 N.m (4.5 lb-in) (tighten using screwdriver diam. 3.5 mm) |

General characteristics

Protection rating IP00

11/03/2013 www.crouzet.com
Processing characteristics of CB, CD, XD & XB product types

| Programming method Program size 350 tyr 128 ms 256 blo Program memory Removable memory Pata memory Program memory Rack-up time in the event of power failure Program | its/200 words am and settings in the controller : 10 years am and settings in the plug-in memory : 10 years memory : 10 years er : typically 20 ms 6 →90 ms acquisition time + 1 to 2 cycle times ars (lithium battery) at 25 °C 12 min/year (at 25 °C) onth (at 25 °C with user-definable correction of drift) 2 cycle times s AC / +20 % 4 V AC→28.8 V AC Hz (+4 % / -6 %) →53 Hz/57 →63 Hz (repetition 20 times) | 100 →240 V AC -15 % / +10 % or 85 V AC→264 V AC 50/60 Hz (+ 4 % / - 6 %) or 47 →53 Hz/57 →63 Hz |
|--|---|--|
| Program size 350 tyr 128 ms 256 blc Program memory Removable memory Removable memory Reack-up time in the event of power failure Program Pro | prical blocks lacros maximum locks maximum per macro EEPROM DM its/200 words am and settings in the controller : 10 years am and settings in the plug-in memory : 10 years am and settings in the plug-in memory : 10 years am emory : 10 years er : typically 20 ms 6 ~90 ms acquisition time + 1 to 2 cycle times ars (lithium battery) at 25 °C 12 12 min/year (at 25 °C) onth (at 25 °C with user-definable correction of drift) 2 cycle times s AC / +20 % 4 V AC—28.8 V AC Hz (+4 % / -6 %) →53 Hz/57 →63 Hz (repetition 20 times) | -15 % / +10 % or 85 V AC→264 V AC |
| 128 ma 256 blc Program memory Removable memory Removable memory Removable memory Removable memory Resolve time in the event of power failure Response time Response Response time Response Response time Response R | acros maximum locks maximum per macro EEPROM DM its/200 words am and settings in the controller : 10 years am and settings in the plug-in memory : 10 years am and settings in the plug-in memory : 10 years are: typically 20 ms 6 →90 ms acquisition time + 1 to 2 cycle times are: (lithium battery) at 25 °C at 2 min/year (at 25 °C) at 25 °C with user-definable correction of drift) 2 cycle times s AC / +20 % 4 V AC→28.8 V AC Hz (+4 % / -6 %) →53 Hz/57 →63 Hz (repetition 20 times) | -15 % / +10 % or 85 V AC→264 V AC |
| 256 blo Program memory Removable memory Removable memory Removable memory Removable memory Reack-up time in the event of power failure Response time Response Response time Response | locks maximum per macro EEPROM DM its/200 words am and settings in the controller : 10 years am and settings in the plug-in memory : 10 years memory : 10 years er : typically 20 ms 6 →90 ms acquisition time + 1 to 2 cycle times ars (lithium battery) at 25 °C 12 min/year (at 25 °C) onth (at 25 °C with user-definable correction of drift) 2 cycle times s AC / +20 % 4 V AC→28.8 V AC Hz (+4 % / -6 %) →53 Hz/57 →63 Hz (repetition 20 times) | -15 % / +10 % or 85 V AC→264 V AC |
| Program memory Removable memory Rescription Rescription Response time Response Response time Response R | DM DM DM DM DM DM DM DIM DIM DIM DIM DIM | -15 % / +10 % or 85 V AC→264 V AC |
| Removable memory Removable memory Reack-up time in the event of power failure Response time Response | om its/200 words am and settings in the controller : 10 years am and settings in the plug-in memory : 10 years am and settings in the plug-in memory : 10 years am and settings in the plug-in memory : 10 years am emory : 10 years ar : typically 20 ms 6 ->90 ms acquisition time + 1 to 2 cycle times ars (lithium battery) at 25 °C 12 min/year (at 25 °C) onth (at 25 °C with user-definable correction of drift) 2 cycle times s AC / +20 % 4 V AC->28.8 V AC Hz (+4 % / -6 %) ->53 Hz/57 ->63 Hz (repetition 20 times) | -15 % / +10 % or 85 V AC→264 V AC |
| Pack-up time in the event of power failure Progra Progra Progra Data m Progra Progra Progra Data m Progra Progra Progra Data m Progra Progra Data m Progra Progra Data m Progra P | its/200 words am and settings in the controller : 10 years am and settings in the plug-in memory : 10 years memory : 10 years er : typically 20 ms 6 →90 ms acquisition time + 1 to 2 cycle times ars (lithium battery) at 25 °C 12 min/year (at 25 °C) onth (at 25 °C with user-definable correction of drift) 2 cycle times s AC / +20 % 4 V AC→28.8 V AC Hz (+4 % / -6 %) →53 Hz/57 →63 Hz (repetition 20 times) | -15 % / +10 % or 85 V AC→264 V AC |
| Ack-up time in the event of power failure Progra Pr | am and settings in the controller : 10 years am and settings in the plug-in memory : 10 years memory : 10 years er: typically 20 ms 6 ->90 ms acquisition time + 1 to 2 cycle times ars (lithium battery) at 25 °C | -15 % / +10 % or 85 V AC→264 V AC |
| Progra Data m Data m Ladder FBD : 6 Response time Input a Clock data retention Clock drift Drift < 6 s/mo Cimer block accuracy 1 % ± 1 6 s/mo Clarat up time on power up Arracteristics of products with AC power supplied upply Impuly I | am and settings in the plug-in memory: 10 years memory: 10 years er: typically 20 ms 6 ~90 ms acquisition time + 1 to 2 cycle times ars (lithium battery) at 25 °C 12 min/year (at 25 °C) onth (at 25 °C with user-definable correction of drift) 2 cycle times s AC / +20 % 4 V AC—28.8 V AC Hz (+4 % / -6 %) —53 Hz/57 —63 Hz (repetition 20 times) | -15 % / +10 % or 85 V AC→264 V AC |
| Data in Data in Ladder FBD : 6 Ladde | memory: 10 years er: typically 20 ms 6 →90 ms acquisition time + 1 to 2 cycle times ara; (lithium battery) at 25 °C at 12 min/year (at 25 °C) onth (at 25 °C with user-definable correction of drift) 2 cycle times s AC / +20 % 4 V AC→28.8 V AC Hz (+4 % / -6 %) →53 Hz/57 →63 Hz (repetition 20 times) | -15 % / +10 % or 85 V AC→264 V AC |
| Response time Input a Clock data retention 10 yea Clock drift Drift < 6 s/mo Clock drift C start up time on power up < 1,2 s Characteristics of products with AC power supplied Upply Clominal voltage 24 V A Operating limits -15 % Or 20.4 Couply frequency range 50/60 h Or 47 - Coupling from micro power cuts 10 ms Max. absorbed power CCB20- CCB2 | 6 → 90 ms acquisition time + 1 to 2 cycle times ars (lithium battery) at 25 °C 12 min/year (at 25 °C) onth (at 25 °C with user-definable correction of drift) 2 cycle times s AC / +20 % 4 V AC→28.8 V AC Hz (+4 % / -6 %) →53 Hz/57 →63 Hz (repetition 20 times) | -15 % / +10 % or 85 V AC→264 V AC |
| Input a Inpu | acquisition time + 1 to 2 cycle times ars (lithium battery) at 25 °C 12 min/year (at 25 °C) onth (at 25 °C with user-definable correction of drift) 2 cycle times s AC / +20 % 4 V AC—28.8 V AC Hz (+4 % / -6 %) —53 Hz/57 —63 Hz (repetition 20 times) | -15 % / +10 % or 85 V AC→264 V AC |
| 10 year 20ck data retention 10 year 20ck drift | ars (lithium battery) at 25 °C 12 min/year (at 25 °C) onth (at 25 °C with user-definable correction of drift) 2 cycle times s AC / +20 % 4 V AC—28.8 V AC Hz (+4 % / -6 %) —53 Hz/57 —63 Hz (repetition 20 times) | -15 % / +10 % or 85 V AC→264 V AC |
| Clock drift Clock | 12 min/year (at 25 °C) onth (at 25 °C with user-definable correction of drift) 2 cycle times s AC / +20 % 4 V AC→28.8 V AC Hz (+4 % / -6 %) →53 Hz/57 →63 Hz (repetition 20 times) | -15 % / +10 % or 85 V AC→264 V AC |
| 6 s/mo fimer block accuracy 1 % ± 2 start up time on power up 4 1,2 s haracteristics of products with AC power supplied upply lominal voltage 24 V A Operating limits -15 % or 20.4 supply frequency range 50/60 B or 47 - mmunity from micro power cuts fax. absorbed power CB12-0 CB20-(XD10-) | onth (at 25 °C with user-definable correction of drift) 2 cycle times AC / +20 % 4 V AC →28.8 V AC Hz (+4 % / -6 %) →53 Hz/57 →63 Hz (repetition 20 times) | -15 % / +10 % or 85 V AC→264 V AC |
| imer block accuracy Start up time on power up * 1,2 s tharacteristics of products with AC power supplied upply Jominal voltage Operating limits * 15 % or 20.4 Supply frequency range * 50/60 H or 47 - mmunity from micro power cuts Aax. absorbed power CB12-0 CB20-0 XD10-> | 2 cycle times S AC / +20 % 4 V AC →28.8 V AC Hz (+4 % / -6 %) →53 Hz/57 →63 Hz (repetition 20 times) | -15 % / +10 % or 85 V AC→264 V AC |
| Start up time on power up haracteristics of products with AC power supplied upply lominal voltage 24 V A Operating limits -15 % or 20.4 Supply frequency range 50/60 B or 47 - mmunity from micro power cuts fax. absorbed power CB12-0 CB20-0 XD10-> | AC / +20 % 4 V AC →28.8 V AC Hz (+4 % / -6 %) →53 Hz/57 →63 Hz (repetition 20 times) | -15 % / +10 % or 85 V AC→264 V AC |
| haracteristics of products with AC power supplied upply lominal voltage 24 V A Operating limits -15 % or 20.4 Supply frequency range 50/60 h or 47 - mmunity from micro power cuts 10 ms Max. absorbed power CB12-0 CB20-0 XD10-> | AC / +20 % 4 V AC→28.8 V AC Hz (+4 % / -6 %) →53 Hz/57 →63 Hz (repetition 20 times) | -15 % / +10 % or 85 V AC→264 V AC |
| Lupply Lominal voltage 24 V A Operating limits -15 % or 20.4 Supply frequency range 50/60 H or 47 - mmunity from micro power cuts Aax. absorbed power CB12-0 CB20-0 XD10-> | / +20 % 4 V AC→28.8 V AC Hz (+4 % / -6 %) →53 Hz/57 →63 Hz (repetition 20 times) | -15 % / +10 % or 85 V AC→264 V AC |
| Lupply Lominal voltage 24 V A Operating limits -15 % or 20.4 Supply frequency range 50/60 H or 47 - mmunity from micro power cuts Aax. absorbed power CB12-0 CB20-0 XD10-> | / +20 % 4 V AC→28.8 V AC Hz (+4 % / -6 %) →53 Hz/57 →63 Hz (repetition 20 times) | -15 % / +10 % or 85 V AC→264 V AC |
| Department Dep | / +20 % 4 V AC→28.8 V AC Hz (+4 % / -6 %) →53 Hz/57 →63 Hz (repetition 20 times) | -15 % / +10 % or 85 V AC→264 V AC |
| Operating limits -15 % or 20.4 Supply frequency range 50/60 H or 47 - mmunity from micro power cuts 10 ms Aax. absorbed power CB20-CB20-CXD10-X | / +20 % 4 V AC→28.8 V AC Hz (+4 % / -6 %) →53 Hz/57 →63 Hz (repetition 20 times) | -15 % / +10 % or 85 V AC→264 V AC |
| or 20.4 Supply frequency range 50/60 H or 47 - mmunity from micro power cuts 10 ms Aax. absorbed power CB20-6 XD10-3 | 4 V AC→28.8 V AC Hz (+4 % / -6 %) →53 Hz/57 →63 Hz (repetition 20 times) | or 85 V AC→264 V AC |
| Supply frequency range 50/60 h or 47 – mmunity from micro power cuts 10 ms flax. absorbed power CB12-C CB20-C XD10-X | Hz (+4 % / -6 %) →53 Hz/57 →63 Hz (repetition 20 times) | |
| or 47 – mmunity from micro power cuts 10 ms fax. absorbed power CB12-C CB20-C XD10-X | →53 Hz/57 →63 Hz (repetition 20 times) | 50/60 Hz (+ 4 % / - 6 %) or 47 →53 Hz/57 →63 Hz |
| mmunity from micro power cuts 10 ms CB12-C CB20-C XD10-X | (repetition 20 times) | |
| flax. absorbed power CB12-CCB20-CXD10-X | ` ' | 10 ms (repetition 20 times) |
| CB20-C XD10-> | CD12-XD10-XB10 : 4 VA | CB12-CD12-XD10-XB10 : 7 VA |
| | CD20 : 6 VA | CB20-CD20 : 11 VA |
| | XB10 with extension - XD26-XB26 : 7.5 VA | XD10-XB10 with extension - XD26-XB26 : 12 VA |
| XD26-> | XB26 with extension : 10 VA | XD26-XB26 with extension : 17 VA |
| solation voltage 1780 V | V AC | 1780 V AC |
| puts | | |
| | AC (-15 % / +20 %) | 100 →240 V AC (-15 % / +10 %) |
| | A @ 20.4 V AC | |
| | A @ 24.0 V AC | 0.24 mA @ 85 V AC |
| | A @ 28.8 V AC | 0.75 mA @ 264 V AC |
| nput impedance 4.6 kΩ | | 350 kΩ |
| ogic 1 voltage threshold ≥ 14 V | / AC | ≥ 79 V AC |
| Making current at logic state 1 > 2 mA | 4 | > 0.17 mA |
| ogic 0 voltage threshold ≤ 5 V A | AC | ≤ 20 V AC (≤ 28 V AC : XE10, XR06, XR10, XR14) |
| Release current at logic state 0 < 0.5 m | mA | < 0.5 mA |
| Response time with LADDER programming 50 ms | | 50 ms |
| | 0 →1 (50/60 Hz) | State 0 →1 (50/60 Hz) |
| | gurable in increments of 10 ms | Configurable in increments of 10 ms |
| | min. up to 255 ms | 50 ms min. up to 255 ms |
| | 0 →1 (50/60 Hz) | State $0 \rightarrow 1$ (50/60 Hz) |
| | ordance with cycle time (Tc) and input response time (Tr): | In accordance with cycle time (Tc) and input response time (Tr): |
| | x Tc) + Tr) ct or 3-wire PNP | 1/ ((2 x Tc) + Tr) Contact or 3-wire PNP |
| 71 | | Contact or 3-wire PNP Resistive |
| nput type Resisti | IIAC | |
| solation between power supply and inputs None | | None |
| Solation between inputs None Protection against polarity invargions | | None |
| Protection against polarity inversions Yes Status indicator On LCI | D coroon for CD and VD | Yes On LCD screen for CD and XD |
| | CD screen for CD and XD | OIL LOD Screen for OD and XD |
| haracteristics of relay outputs common to the entire rai | | |
| 3 3 3 |) V DC | |
| | 250 V AC | |
| | D-XD10-XB10-XR06-XR10 : 8 A | |
| | ·XB26:8 x 8 A relays, 2 x 5 A relays | |
| | : 4 x 5 A relays : 4 x 8 A relays, 2 x 5 A relays | |
| | Removable Terminal Blocks) versions : verify the maximum of | urrent according to the type of connection used |
| • | tion category DC-12 : 24 V, 1.5 A | , , , , , , , , , , , , , , , , , , , |
| | tion category DC-13 : 24 V (L/R = 10 ms), 0.6 A | |
| | tion category AC-12 : 230 V, 1.5 A | |
| | tion category AC-15 : 230 V, 0.9 A | |
| Max. Output Common Current 12 A fo | or O8, O9, OA | |
| finimum switching capacity 10 mA | A (at minimum voltage of 12 V) | |
| | 10 mA | |
| | ad : 10 Hz | |
| · | erating current : 0.1 Hz | |
| | 0,000 (operations) | |
| | ordance with IEC/EN 60947-1 and IEC/EN 60664-1: 4 kV | |
| Response time Make 1 | | |
| | se 5 ms | |
| | st short-circuits : None | |
| - | st overvoltages and overloads : None CD screen for CD and XD | |

11/03/2013 www.crouzet.com

Characteristics of product with DC power supplied

| Supply | 40 V DC | 24 V D2 | | |
|---|---|--------------------------------------|---|--|
| Nominal voltage Operating limits | 12 V DC 24 V DC -20 % / +25 % | | | |
| Operating litting | or 10.4 V DC→14.4 V DC (including ripple) | -20 % / +25 % or 19.2 V DC→30 V [| DC (including ripple) | |
| Immunity from micro power cuts | ≤ 1 ms (repetition 20 times) | ≤ 1 ms (repetition 20 | | |
| Max. absorbed power | CB12 with solid state outputs : 1.5 W | CB12-CD12-CD20 wi | th solid state outputs - XD10-XB10 with solid state outputs : 3 W | |
| | CD12 : 1.5 W | XD10-XB10 with rela | | |
| | CD20: 2.5 W | XD26-XB26 with solid | | |
| | XD26-XB26: 3 W XD26-XB26 with extension: 5 W | XD10-XB10 with exte | y outputs - XD26 with relay outputs : 6 W ension : 8 W | |
| | XD26-XD26 with extension . 5 W XD10-XD10 with ex XD26 with solid state outputs : 2.5 W XD26-XB26 with ex | | | |
| Protection against polarity inversions | Yes | Yes | | |
| Digital inputs (I1 to IA and IH to IY) | | | | |
| nput voltage | 12 V DC (-13 % / +20 %) | | 24 V DC (-20 % / +25 %) | |
| nput current | 3.9 mA @ 10.44 V DC | | 2.6 mA @ 19.2 V DC | |
| | 4.4 mA @ 12.0 V DC | | 3.2 mA @ 24 V DC | |
| | 5.3 mA @ 14.4 VDC | | 4.0 mA @ 30.0 VDC | |
| Input impedance | 2.7 kΩ | | 7.4 kΩ | |
| Logic 1 voltage threshold Making current at logic state 1 | ≥ 7 V DC ≥ 2 mA | | ≥ 15 V DC ≥ 2.2 mA | |
| Logic 0 voltage threshold | ≤3 V DC | | ≤ 5 V DC | |
| Release current at logic state 0 | < 0.9 mA | | < 0.75 mA | |
| Response time | 1 →2 cycle times | | 1 →2 cycle times | |
| Maximum counting frequency | Inputs I1 & I2 : Ladder (1 k Hz) & FBD (up to | 6 k Hz) | Inputs I1 & I2 : Ladder (1 k Hz) & FBD (up to 6 k Hz) | |
| | Inputs I3 to IA & IH to IY: In accordance with input response time (Tr): 1/((2 x Tc) + Tr) | | Inputs I3 to IA & IH to IY : In accordance with cycle time (Tc) and input response time (Tr) : $1/((2 \times Tc) + Tr)$ | |
| Sensor type | Contact or 3-wire PNP | | Contact or 3-wire PNP | |
| Conforming to IEC/EN 61131-2 | Type 1 | | Type 1 | |
| nput type | Resistive | | Resistive | |
| solation between power supply and inputs | None | | None | |
| solation between inputs | None | | None | |
| Protection against polarity inversions | Yes | | Yes | |
| Status indicator | On LCD screen for CD and XD | | On LCD screen for CD and XD | |
| analogue or digital inputs (IB to IG) | | | | |
| CB12-CD12-XD10-XB10 | 4 inputs IB →IE | | 4 inputs IB →IE | |
| CB20-CD20-XB26-XD26 | 6 inputs IB →IG | | 6 inputs IB →IG | |
| nputs used as analogue inputs | | | | |
| Measurement range | $(0 \rightarrow 10 \text{ V})$ or $(0 \rightarrow \text{V})$ power supply) | | $(0 \rightarrow 10 \text{ V})$ or $(0 \rightarrow \text{V power supply})$ | |
| nput impedance | 14 kΩ | | 12 kΩ | |
| Input voltage | 14.4 V DC max. | | 30 V DC max. | |
| Value of LSB | 14 mV, 4 mA Common mode | | 29 mV, 4 mA Common mode | |
| nput type Resolution | 10 bits at max. input voltage | | 10 bits at max. input voltage | |
| Conversion time | Controller cycle time | | Controller cycle time | |
| Accuracy at 25 °C | ±5% | | ±5% | |
| Accuracy at 55 °C | ± 6.2 % | | ± 6.2 % | |
| Repeat accuracy at 55 °C | ± 2 % | | ± 2 % | |
| solation between analogue channel and power supply | None | | None | |
| Cable length | 10 m maximum, with shielded cable (sensor | not isolated) | 10 m maximum, with shielded cable (sensor not isolated) | |
| Protection against polarity inversions | Yes | | Yes | |
| Potentiometer control | 2.2 kΩ/0.5 W (recommended) 10 kΩ max. | | $2.2~k\Omega/0.5~W$ (recommended) $10~k\Omega$ max. | |
| nputs used as digital inputs | Lava | | | |
| nput current | 12 V DC (-13 % / +20 %) | | 24 V DC (-20 % / +25 %) | |
| nput current | 0.7 mA @ 10.44 VDC 0.9 mA @ 12.0 VDC | | 1.6 mA @ 19.2 VDC 2.0 mA @ 24.0 V DC | |
| | 1.0 mA @ 14.4VDC | | 2.5 mA @ 30.0 VDC | |
| nput impedance | 14 kΩ | | 12 kΩ | |
| Logic 1 voltage threshold | ≥ 7 V DC | | ≥ 15 VDC | |
| Making current at logic state 1 | ≥ 0.5 mA | | ≥ 1.2 mA | |
| ogic 0 voltage threshold | ≤3 V DC | | ≤5 V DC | |
| Release current at logic state 0 | ≤ 0.2 mA | | ≤ 0.5 mA | |
| Response time | 1 →2 cycle times | roonanaa ti (T-) | 1 →2 cycle times | |
| Maximum counting frequency | In accordance with cycle time (Tc) and input 1/ ((2 x Tc) + Tr) | response time (1r): | In accordance with cycle time (Tc) and input response time (Tr) 1/ ((2 x Tc) + Tr) | |
| Sensor type | Contact or 3-wire PNP | | Contact or 3-wire PNP | |
| Conforming to IEC/EN 61131-2 | Type 1 | | Type 1 | |
| nput type | Resistive | | Resistive | |
| solation between power supply and inputs | None None | | None None | |
| solation between inputs Protection against polarity inversions | Yes | | Yes | |
| Status indicator | On LCD screen for CD and XD | | On LCD screen for CD and XD | |
| Characteristics of relay outputs common to the e | | | | |
| | 5 →30 V DC | | | |
| Max. breaking voltage | | | | |
| Max. breaking voltage | 24 →250 V AC | | | |

11/03/2013 www.crouzet.com

| Breaking current | CB-CD-XD10-XB10-XR06-XR10 : 8 A XD26-XB26 : 8 x 8 A relays, 2 x 5 A relays XE10 : 4 x 5 A relays XR14 : 4 x 8 A relays, 2 x 5 A relays | | |
|--|--|--|--|
| Electrical durability for 500 000 operating cycles | Utilization category DC-12: 24 V, 1.5 A Utilization category DC-13: 24 V (L/R = 10 ms), 0.6 A Utilization category AC-12: 230 V, 1.5 A Utilization category AC-15: 230 V, 0.9 A | | |
| Minimum switching capacity | 10 mA (at minimum voltage of 12 V) | | |
| Minimum load | 12 V, 10 mA | | |
| Maximum rate | Off load : 10 Hz At operating current : 0.1 Hz | | |
| Mechanical life | 10,000,000 (operations) | | |
| Voltage for withstanding shocks | In accordance with IEC/EN 60947-1 and IEC/EN 60664-1 : 4 kV | | |
| Response time | Make 10 ms Release 5 ms | | |
| Built-in protections | Against short-circuits : None Against overvoltages and overloads : None | | |
| Status indicator | On LCD screen for CD and XD | | |
| Digital / PWM solid state output | | | |
| PWM solid state output* | CB12 : O4 XD26 : O4 →O7 | CD12-XD10-XB10 : O4 CD20-XD26-XB26 : O4 →O7 | |
| * Only available with "FBD" programming language | * Only available with "FBD" programming language | | |
| Breaking voltage | 10.4 →30 V DC | 19.2 →30 V DC | |
| Nominal voltage | 12-24 VDC | 24 V DC | |
| Nominal current | 0.5 A | 0.5 A | |
| Max. breaking current | 0,625 A | 0,625 A | |
| Voltage drop | ≤ 2 V for I = 0.5 A (at state 1) | ≤ 2 V for I = 0.5 A (at state 1) | |
| Response time | Make ≤ 1 ms Release ≤ 1 ms | Make ≤ 1 ms Release ≤ 1 ms | |
| Frequency (Hz) | | | |
| Built-in protections | Against overloads and short-circuits: Yes Against overvoltages (*): Yes Against inversions of power supply: Yes (*) In the absence of a volt-free contact between the logic controller output and the load | Against overloads and short-circuits: Yes Against overvoltages (*): Yes Against inversions of power supply: Yes (*) In the absence of a volt-free contact between the logic controller output and the load | |

1 mA

No

14.11 Hz

56.45 Hz

112.90 Hz

225.80 Hz 451.59 Hz

1806.37 Hz

50 mA

20

 $0 \rightarrow 100$ % (256 steps for CD, XD and 1024 steps for XA)

< 5 % (20 % \rightarrow 80 %) load at 10 mA

< 10 % (20 % →80 %) load at 10 mA

On LCD screen for CD and XD

0,1 A / 24 V DC

Accessories

Status indicator

Galvanic isolation

PWM cyclic ratio

Max. Breaking current PWM

Max. cable length PWM (m)

PWM accuracy at 120 Hz

PWM accuracy at 500 Hz

PWM frequency

| Туре | Description | Code |
|---------|--|----------|
| M3 SOFT | Multilingual programming software containing specific library functions (CD-ROM) | 88970111 |
| PA | EEPROM memory cartridge | 88970108 |
| PA | 3 m serial link cable : PC →Millenium 3 | 88970102 |
| PA | USB cable 3 m : PC →Millenium 3 | 88970109 |
| PA | Millenium 3 interface →Bluetooth (class A 10 m) | 88970104 |

 $0 \rightarrow 100$ % (256 steps for CD, XD and 1024 steps for XA)

< 5 % (20 % \rightarrow 80 %) load at 10 mA

< 10 % (20 % \rightarrow 80 %) load at 10 mA

On LCD screen for XD

Dimensions (mm)

NB20

1 mA 0,2 A / 12 V DC

No

14.11 Hz

56.45 Hz

112.90 Hz

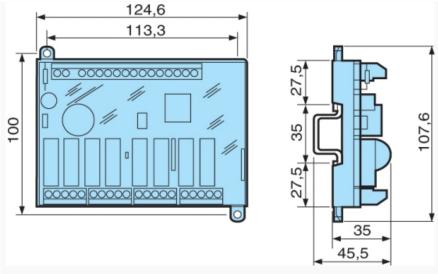
225.80 Hz

451.59 Hz 1806.37 Hz

50 mA

20

0,1 A / 24 V DC



mm

Product adaptations



- Tropicalisation
- Spring connectors or removable connectors
 Changing the number of I/O
 Updating power supply